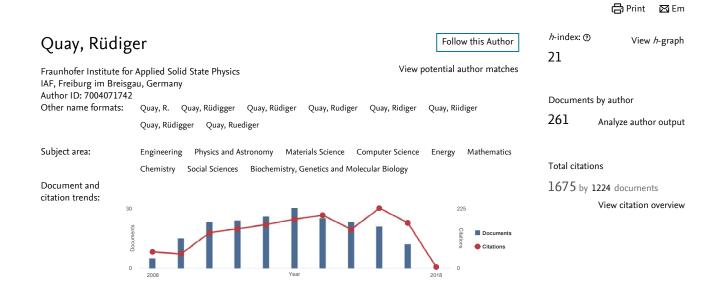
Scopus

Author details

261 Documents

About Scopus Author Identific



150 co-authors

Author history

 $\ \ \, \ \, \textcircled{Get citation alerts} \ \, + \text{Add to ORCID} \, \textcircled{\scriptsize 0} \ \, \ \, \nearrow_{\hspace{-0.5em} \textbf{Request author detail corrections}}$

Cited by 1224 documents

| View all in search results format > | | | Sort on: Date (newest) | ~ |
|---|--|------|--|----------|
| Export all Add all to list Set document aler | t Set document feed | | | |
| Document title | Authors | Year | Source | Cited by |
| Radiation aspects and performance of GaN power converters and RFICs for airborne and space applications | Quay, R., Bruckner, P., Reiner, R., Schwantuschke, D., Waltereit, P. | 2017 | IEEE MTT-S International Microwave Symposium Diges 8059006, pp. 1826-1829 | t (|
| View abstract ✓ View at Publisher Find it ⑤ NT | Related documents | | | |
| First demonstration of W-band Tri-gate GaN- HEMT power amplifier MMIC with 30 dBm output power | Ture, E., Bruckner, P., Alsharef, M., (), Quay, R., Ambacher, O. | 2017 | IEEE MTT-S International Microwave Symposium Diges 8058452, pp. 35-37 | t (|
| View abstract ✓ View at Publisher Find it ⑤ NT | Related documents | | | |
| Reliability of 100 nm AlGaN/GaN HEMTs for mm- wave applications | Dammann, M., Baeumler, M., Polyakov, V., (), Graff, A., Simon- Najasek, M. | 2017 | Microelectronics Reliability 76-77, pp. 292-297 | (|
| View abstract ✓ View at Publisher Find it ⑤ NT | Related documents | | | |
| AIN/GaN HEMTs grown by MBE and MOCVD: Impact of AI distribution | Godejohann, BJ., Ture, E., Müller, S., (), Quay, R., Ambacher, O. | 2017 | Physica Status Solidi (B) Basic Research 254(8),1600715 |] |
| View abstract ✓ View at Publisher Find it ⑤ NT | U Related documents | | | |
| Design, Realization, and Evaluation of a Riemann Pump in GaN Technology | Weib, M., Friesicke, C., Metzger, T., (), Quay, R., Ambacher, O. | 2017 | IEEE Microwave and Wireless Components Letters 27(7),7955083, pp. 672-674 | (|
| View abstract ✓ View at Publisher Find it ⑤ NT | Related documents | | | |
| New concept for power compression improvemen of GaN cascodes in broadband power amplifiers | t Huber, T., Quay, R., Bösch, W. | 2017 | IEEE Microwave and Wireless Components Letters 27(6),7934018, pp. 590-592 | (|

| Document title | Authors | Year | Source | Cited |
|--|--|------|--|-------|
| /iew abstract ✓ View at Publisher Find it ⊙ NTU | Related documents | | | |
| Multi-decade GaN feedback power amplifiers in common-source and cascode topology | Huber, T., Quay, R., Bosch, W. | 2017 | Asia-Pacific Microwave Conference Proceedings, APMC 7931347 | |
| /iew abstract ✓ View at Publisher Find it ⑤ NTU | Related documents | | | |
| Noise degradation of cascodes in broadband lower amplifiers | Huber, T., Quay, R., Bosch, W. | 2017 | Proceedings of the 2017 International Workshop on Integrated Nonlinear Microwave and Millimetre-Wave Circuits, INMMiC 2017 7927298 | |
| 'iew abstract ✓ View at Publisher Find it ⑤ NTU | Related documents | | | |
| Hetero-integrated GaN MMICs: Hot Islands in a Silicon) Ocean… | Quay, R., Bruckner, P., Tessmann, A., (), Dammann, M., Waltereit, P. | 2017 | Proceedings of the 2017 International Workshop on Integrated Nonlinear Microwave and Millimetre-Wave Circuits, INMMiC 2017 7927326 | |
| 'iew abstract ∨ View at Publisher Find it ⑤ NTU | Related documents | | | |
| Enhancement of the Broadband Efficiency of a Class-J Power Amplifier with Varactor-based Dynamic Load Modulation | Amirpour, R., Darraji, R., Ghannouchi, F., Quay, R. | 2017 | IEEE Microwave and Wireless Components Letters 27(2),7829255, pp. 180-182 | |
| /iew abstract ✓ View at Publisher Find it ⑤ NTU | Related documents | | | |
| Demonstration of an RF front-end based on GaN HEMT technology | Ture, E., Musser, M., Hülsmann, A., Quay, R., Ambacher, O. | 2017 | Proceedings of SPIE - The International Society for Optical Engineering 10184,101840V | |
| /iew abstract ✓ View at Publisher Find it 彡 NTU | Related documents | | | |
| suppression of Iron Memory Effect in GaN pitaxial Layers | Leone, S., Benkhelifa, F., Kirste, L., (), Quay, R., Stadelmann, T. | 2017 | Physica Status Solidi (B) Basic Research Article in Press | |
| /iew abstract ✓ View at Publisher Find it ⑤ NTU | | | | |
| ioft-switching 3 MHz converter based on nonolithically integrated half-bridge GaN-chip | Weiss, B., Reiner, R., Waltereit, P., (), Sepahvand, A., Maksimovic, D. | 2016 | WiPDA 2016 - 4th IEEE Workshop on Wide Bandgap Power Devices and Applications 7799940, pp. 215-219 | |
| /iew abstract ✓ View at Publisher Find it ⊙ NTU | Related documents | | | |
| Single-input GaN gate driver based on depletion- mode logic integrated with a 600 v GaN-on-Si power transistor | Moench, S., Kallfass, I., Reiner, R., (), Quay, R., Ambacher, O. | 2016 | WiPDA 2016 - 4th IEEE Workshop on Wide Bandgap Power Devices and Applications 7799938, pp. 204-209 | |
| /iew abstract ✓ View at Publisher Find it ⑤ NTU | Related documents | | | |
| Slew rate control of a 600 v 55 m Ω GaN cascode | Endruschat, A., Heckel, T., Reiner, R., (), Eckardt, B., Frey, L. | 2016 | WiPDA 2016 - 4th IEEE Workshop on Wide Bandgap Power Devices and Applications 7799963, pp. 334-339 | |
| /iew abstract ✓ View at Publisher Find it ⑤ NTU | Related documents | | | |
| a Q-band power amplifier MMIC using 100 nm IIGaN/GaN HEMT | Feuerschütz, P., Friesicke, C., Quay, R., Jacob, A.F. | 2016 | EuMIC 2016 - 11th European Microwave Integrated Circuits Conference 7777551, pp. 305-308 | |
| /iew abstract ✓ View at Publisher Find it ⑤ NTU | Related documents | | | |
| Oual-gate HEMT parameter extraction based on 2.5D multiport simulation of passive structures | Van Raay, F., Quay, R., Schwantuschke, D., (), Schlechtweg, M., Ambacher, O. | 2016 | EuMIC 2016 - 11th European Microwave Integrated Circuits Conference 7777535, pp. 241-244 | |
| /iew abstract ✓ View at Publisher Find it ⑤ NTU | Related documents | | | |
| nhancement-mode AlGaN/GaN FinFETs with igh on/off performance in 100 nm gate length | Ture, E., Brückner, P., Quay, R., (), Granzner, R., Schwierz, F. | 2016 | EuMIC 2016 - 11th European Microwave Integrated Circuits Conference 7777489, pp. 61-64 | |

| Document title | | Authors | Year Source Cited by |
|--|---|--|--|
| Internally-packaged-ı class-FI wideband Ga | matched continuous inverse N HPA | Carrubba, V., Maroldt, S., Ture, E., (), Quay, R., Ambacher, O. | 2016 EuMIC 2016 - 11th European Microwave Integrated Circuits Conference 7777533, pp. 233-236 |
| View abstract ✓ View | w at Publisher Find it 🥱 NT | Related documents | |
| A GaN-Based 10.1MI Continuous Wave Am Power Applications | Hz Class-F-1 300 W nplifier Targeting Industrial | Maier, F.A., Krausse, D., Gruner, D., (), Quay, R., Ambacher, O. | 2016 Technical Digest - IEEE Compound Semiconductor 1 Integrated Circuit Symposium, CSIC 2016-November,7751019 |
| View abstract ✓ View | w at Publisher Find it 6 NT | U Related documents | |
| 20 N | / results per page | 1 2 3 | 4 5 14 > >> |
| About Scopus | dback, please use the Author Feec | Language | Customer Service |
| What is Scopus | | 日本語に切り替える | Help |
| Content coverage | | 切换到简体中文 | Contact us |
| Scopus blog | | 切換到繁體中文 | |
| Scopus API | | Русский язык | |
| Privacy matters | | | |
| ELSEVIER | Terms and conditions | Privacy policy | |
| | | vier B.V. All rights reserved. Scopus® is | a registered trademark of Elsevier |

Cookies are set by this site. To decline them or learn more, visit our Cookies page.